

# KA5x02xx-SERIES

KA5H0265RC, KA5M0265R, KA5L0265R,  
KA5H02659RN/KA5M02659RN, KA5H0280R,  
KA5M0280R

## Fairchild Power Switch(FPS)

### Features

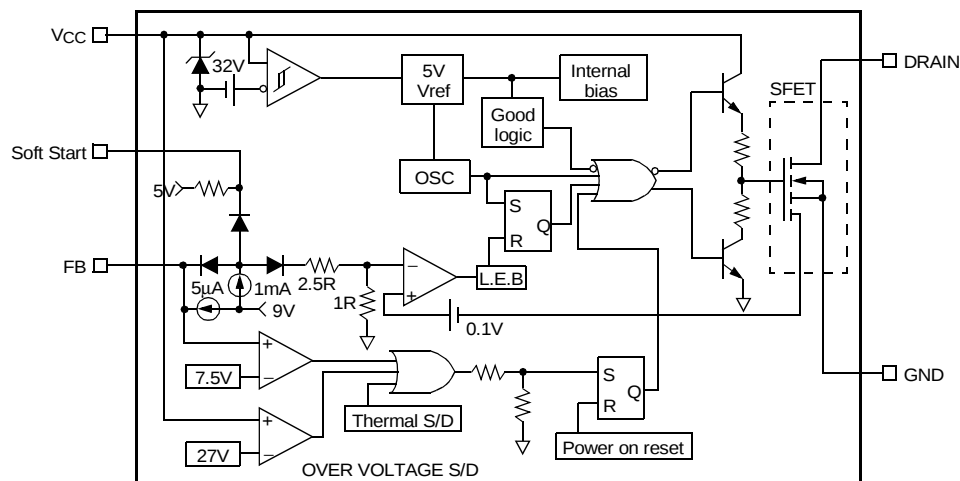
- Precision fixed operating frequency (100/67/50KHz)
- Pulse by pulse current limiting
- Over current protection
- Over voltage protection (Min. 25V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Auto-restart mode

### Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry. compared to discrete MOSFET and controller or RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective design in either a flyback converter or a forward converter.

| TO-220F-4L                                                                           | 8-DIP                                                                                 | TO220-5L                                                                              |
|--------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
|  |  |  |
| 1. GND<br>2. Drain<br>3. Vcc<br>4. FB                                                | 1.6.7.8. Drain<br>2. GND<br>3. Vcc<br>4. FB<br>5. NC                                  | 1. Drain<br>2. GND<br>3. Vcc<br>4. FB<br>5. S/S                                       |

### Internal Block Diagram



Rev.1.0.2

## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

| Characteristic                                   | Symbol              | Value                   | Unit |
|--------------------------------------------------|---------------------|-------------------------|------|
| <b>KA5x0265xRx</b>                               |                     |                         |      |
| Maximum Drain Voltage                            | V <sub>D,MAX</sub>  | 650                     | V    |
| Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)        | V <sub>DGR</sub>    | 650                     | V    |
| Gate-Source (GND) Voltage                        | V <sub>GS</sub>     | ±30                     | V    |
| Drain Current Pulsed <sup>(1)</sup>              | I <sub>DM</sub>     | 8.0                     | ADC  |
| Continuous Drain Current (T <sub>C</sub> =25°C)  | I <sub>D</sub>      | 2.0                     | ADC  |
| Continuous Drain Current (T <sub>C</sub> =100°C) | I <sub>D</sub>      | 1.3                     | ADC  |
| Single Pulsed Avalanche Energy <sup>(2)</sup>    | E <sub>AS</sub>     | 68                      | mJ   |
| Maximum Supply Voltage                           | V <sub>CC,MAX</sub> | 30                      | V    |
| Analog Input Voltage Range                       | V <sub>FB</sub>     | −0.3 to V <sub>SD</sub> | V    |
| Total Power Dissipation                          | P <sub>D</sub>      | 42                      | W    |
|                                                  | Derating            | 0.33                    | W/°C |
| Operating Junction Temperature.                  | T <sub>J</sub>      | +160                    | °C   |
| Operating Ambient Temperature.                   | T <sub>A</sub>      | −25 to +85              | °C   |
| Storage Temperature Range.                       | T <sub>STG</sub>    | −55 to +150             | °C   |
| <b>KA5x0280R</b>                                 |                     |                         |      |
| Maximum Drain Voltage                            | V <sub>D,MAX</sub>  | 800                     | V    |
| Drain-Gate Voltage (R <sub>GS</sub> =1MΩ)        | V <sub>DGR</sub>    | 800                     | V    |
| Gate-Source (GND) Voltage                        | V <sub>GS</sub>     | ±30                     | V    |
| Drain Current Pulsed <sup>(1)</sup>              | I <sub>DM</sub>     | 8.0                     | ADC  |
| Continuous Drain Current (T <sub>C</sub> =25°C)  | I <sub>D</sub>      | 2.0                     | ADC  |
| Continuous Drain Current (T <sub>C</sub> =100°C) | I <sub>D</sub>      | 1.3                     | ADC  |
| Single Pulsed Avalanche Energy <sup>(2)</sup>    | E <sub>AS</sub>     | 90                      | mJ   |
| Maximum Supply Voltage                           | V <sub>CC,MAX</sub> | 30                      | V    |
| Analog Input Voltage Range                       | V <sub>FB</sub>     | −0.3 to V <sub>SD</sub> | V    |
| Total Power Dissipation                          | P <sub>D</sub>      | 35                      | W    |
|                                                  | Derating            | 0.28                    | W/°C |
| Operating Junction Temperature.                  | T <sub>J</sub>      | +160                    | °C   |
| Operating Ambient Temperature.                   | T <sub>A</sub>      | −25 to +85              | °C   |
| Storage Temperature Range.                       | T <sub>STG</sub>    | −55 to +150             | °C   |

**Note:**

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L=51mH, starting T<sub>J</sub>=25°C

## Electrical Characteristics (SFET part)

(Ta=25°C unless otherwise specified)

| Parameter                                           | Symbol  | Condition                                                                                                   | Min. | Typ. | Max. | Unit |
|-----------------------------------------------------|---------|-------------------------------------------------------------------------------------------------------------|------|------|------|------|
| KA5x0265xRx                                         |         |                                                                                                             |      |      |      |      |
| Drain-source breakdown voltage                      | BVDSS   | VGS=0V, ID=50μA                                                                                             | 650  | -    | -    | V    |
| Zero gate voltage drain current                     | IDSS    | VDS=Max. Rating, VGS=0V                                                                                     | -    | -    | 50   | μA   |
|                                                     |         | VDS=0.8Max. Rating, VGS=0V, TC=125°C                                                                        | -    | -    | 200  | μA   |
| Static drain-source on resistance <sup>(note)</sup> | RDS(ON) | VGS=10V, ID=0.5A                                                                                            | -    | 5.0  | 6.0  | Ω    |
| Forward transconductance <sup>(note)</sup>          | gfs     | VDS=50V, ID=0.5A                                                                                            | 1.5  | 2.5  | -    | S    |
| Input capacitance                                   | Ciss    | VGS=0V, VDS=25V, f=1MHz                                                                                     | -    | 550  | -    | pF   |
| Output capacitance                                  | Coss    |                                                                                                             | -    | 38   | -    |      |
| Reverse transfer capacitance                        | Crss    |                                                                                                             | -    | 17   | -    |      |
| Turn on delay time                                  | td(on)  | VDD=0.5BVDSS, ID=1.0A (MOSFET switching time are essentially independent of operating temperature)          | -    | 20   | -    | nS   |
| Rise time                                           | tr      |                                                                                                             | -    | 15   | -    |      |
| Turn off delay time                                 | td(off) |                                                                                                             | -    | 55   | -    |      |
| Fall time                                           | tf      |                                                                                                             | -    | 25   | -    |      |
| Total gate charge (gate-source+gate-drain)          | Qg      | VGS=10V, ID=1.0A, VDS=0.5BVDSS (MOSFET switching time are essentially independent of operating temperature) | -    | -    | 35   | nC   |
| Gate-source charge                                  | Qgs     |                                                                                                             | -    | 3    | -    |      |
| Gate-drain (Miller) charge                          | Qgd     |                                                                                                             | -    | 12   | -    |      |
| KA5x0280R                                           |         |                                                                                                             |      |      |      |      |
| Drain-source breakdown voltage                      | BVDSS   | VGS=0V, ID=50μA                                                                                             | 800  | -    | -    | V    |
| Zero gate voltage drain current                     | IDSS    | VDS=Max. Rating, VGS=0V                                                                                     | -    | -    | 50   | μA   |
|                                                     |         | VDS=0.8Max. Rating, VGS=0V, TC=125°C                                                                        | -    | -    | 200  | μA   |
| Static drain-source on resistance <sup>(note)</sup> | RDS(ON) | VGS=10V, ID=0.5A                                                                                            | -    | 5.6  | 7.0  | Ω    |
| Forward transconductance <sup>(note)</sup>          | gfs     | VDS=50V, ID=0.5A                                                                                            | 1.5  | 2.5  | -    | S    |
| Input capacitance                                   | Ciss    | VGS=0V, VDS=25V, f=1MHz                                                                                     | -    | 250  | -    | pF   |
| Output capacitance                                  | Coss    |                                                                                                             | -    | 52   | -    |      |
| Reverse transfer capacitance                        | Crss    |                                                                                                             | -    | 25   | -    |      |
| Turn on delay time                                  | td(on)  | VDD=0.5BVDSS, ID=1.0A (MOSFET switching time are essentially independent of operating temperature)          | -    | 21   | -    | nS   |
| Rise time                                           | tr      |                                                                                                             | -    | 28   | -    |      |
| Turn off delay time                                 | td(off) |                                                                                                             | -    | 77   | -    |      |
| Fall time                                           | tf      |                                                                                                             | -    | 24   | -    |      |
| Total gate charge (gate-source+gate-drain)          | Qg      | VGS=10V, ID=1.0A, VDS=0.5BVDSS (MOSFET switching time are essentially independent of operating temperature) | -    | -    | 60   | nC   |
| Gate-source charge                                  | Qgs     |                                                                                                             | -    | 15   | -    |      |
| Gate-drain (Miller) charge                          | Qgd     |                                                                                                             | -    | 20   | -    |      |

### Note:

Pulse test: Pulse width ≤ 300μS, duty cycle ≤ 2%

$$S = \frac{1}{R}$$

## Electrical Characteristics (CONTROL part)

(Ta=25°C unless otherwise specified)

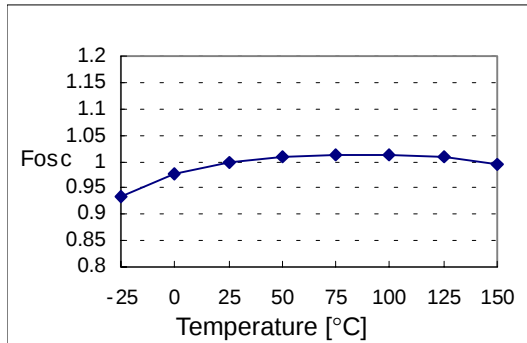
| Parameter                                        | Symbol             | Condition                             | Min. | Typ. | Max. | Unit  |
|--------------------------------------------------|--------------------|---------------------------------------|------|------|------|-------|
| UVLO SECTION                                     |                    |                                       |      |      |      |       |
| Start Threshold Voltage                          | VSTART             | VFB=GND                               | 14   | 15   | 16   | V     |
| Stop Threshold Voltage                           | VSTOP              | VFB=GND                               | 8.4  | 9    | 9.6  | V     |
| OSCILLATOR SECTION                               |                    |                                       |      |      |      |       |
| Initial accuracy                                 | FOSC               | KA5H0265xRx<br>KA5H0280R              | 90   | 100  | 110  | kHz   |
| Initial accuracy                                 | FOSC               | KA5M0265xRx<br>KA5M0280R              | 61   | 67   | 73   | kHz   |
| Initial accuracy                                 | FOSC               | KA5L0265R                             | 45   | 50   | 55   | kHz   |
| Frequency change with temperature <sup>(2)</sup> | ΔF/ΔT              | −25°C ≤ Ta ≤ +85°C                    | -    | ±5   | ±10  | %     |
| Maximum duty cycle                               | Dmax               | KA5H0265xRx<br>KA5H0280R              | 62   | 67   | 72   | %     |
| Maximum duty cycle                               | Dmax               | KA5M0265xRx<br>KA5M0280R<br>KA5L0265R | 72   | 77   | 82   | %     |
| FEEDBACK SECTION                                 |                    |                                       |      |      |      |       |
| Feedback source current                          | IFB                | Ta=25°C, 0V ≤ Vfb ≤ 3V                | 0.7  | 0.9  | 1.1  | mA    |
| Shutdown feedback voltage                        | VSD                | Vfb ≤ 6.5V                            | 6.9  | 7.5  | 8.1  | V     |
| Shutdown delay current                           | Idelay             | Ta=25°C, 5V ≤ Vfb ≤ VSD               | 4    | 5    | 6    | μA    |
| SOFT START SECTION                               |                    |                                       |      |      |      |       |
| Soft Start Voltage                               | VSS                | KA5H0265RC                            | 4.7  | 5.0  | 5.3  | V     |
| Soft Start Current                               | ISS                |                                       | 0.8  | 1.0  | 1.2  | mA    |
| REFERENCE SECTION                                |                    |                                       |      |      |      |       |
| Output voltage <sup>(1)</sup>                    | Vref               | Ta=25°C                               | 4.80 | 5.00 | 5.20 | V     |
| Temperature Stability <sup>(1)(2)</sup>          | Vref/ΔT            | −25°C ≤ Ta ≤ +85°C                    | -    | 0.3  | 0.6  | mV/°C |
| CURRENT LIMIT(SELF-PROTECTION)SECTION            |                    |                                       |      |      |      |       |
| Peak Current Limit                               | I <sub>OVER</sub>  | KA5x02659RN                           | 0.79 | 0.9  | 1.01 | A     |
| Peak Current Limit                               | I <sub>OVER</sub>  | KA5x0265Rx<br>KA5x0280R               | 1.05 | 1.2  | 1.34 | A     |
| PROTECTION SECTION                               |                    |                                       |      |      |      |       |
| Over voltage protection                          | VOVP               | VCC ≥ 24V                             | 25   | 27   | 29   | V     |
| Thermal shutdown temperature (Tj) <sup>(1)</sup> | TSD                | -                                     | 140  | 160  | -    | °C    |
| TOTAL DEVICE SECTION                             |                    |                                       |      |      |      |       |
| Start Up Current                                 | I <sub>START</sub> | VCC=14V                               | -    | 100  | 170  | μA    |
| Operating supply current<br>(control part only)  | I <sub>OPR</sub>   | VCC ≤ 28                              | -    | 7    | 12   | mA    |

**Note:**

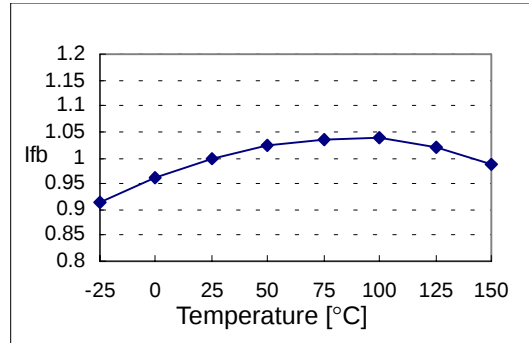
1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

## Typical Performance Characteristics

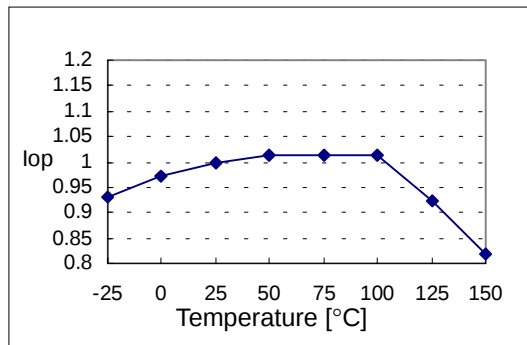
(These characteristic graphs are normalized at  $T_a=25^{\circ}\text{C}$ )



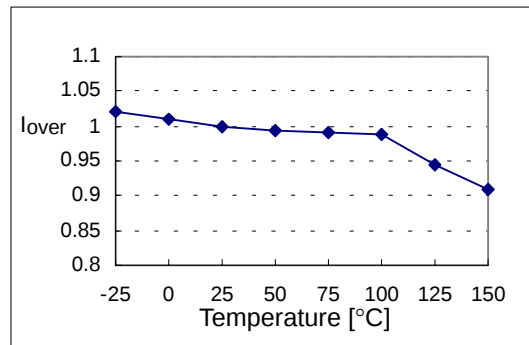
**Figure 1. Operating Frequency**



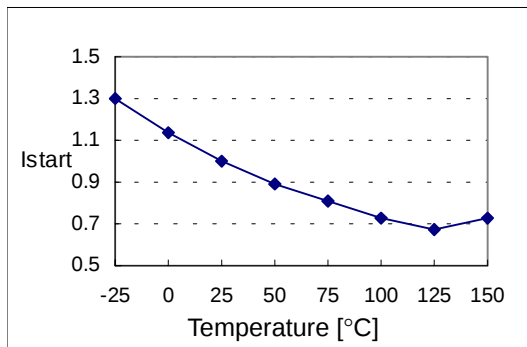
**Figure 2. Feedback Source Current**



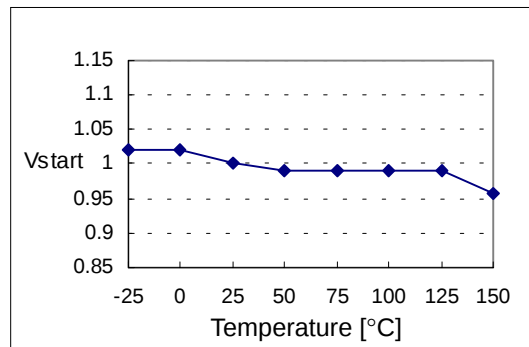
**Figure 3. Operating Supply Current**



**Figure 4. Peak Current Limit**



**Figure 5. Start up Current**



**Figure 6. Start Threshold Voltage**

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

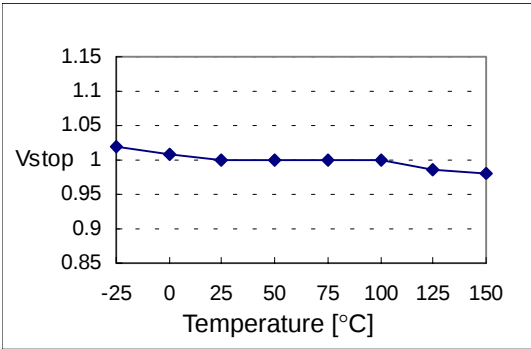


Figure 7. Stop Threshold Voltage

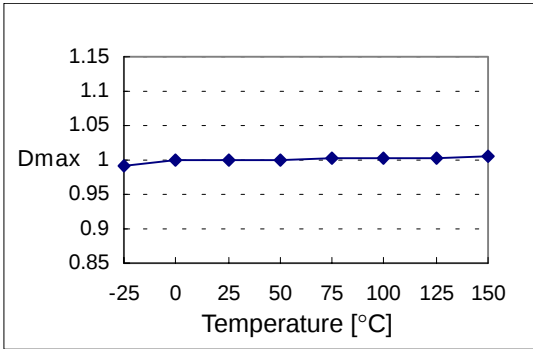


Figure 8. Maximum Duty Cycle

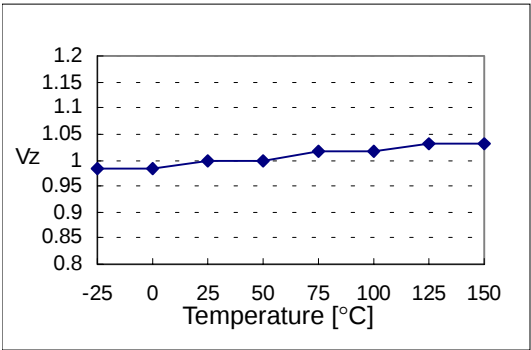


Figure 9. VCC Zener Voltage

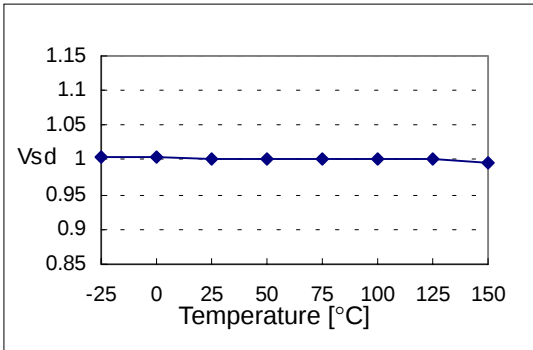


Figure 10. Shutdown Feedback Voltage

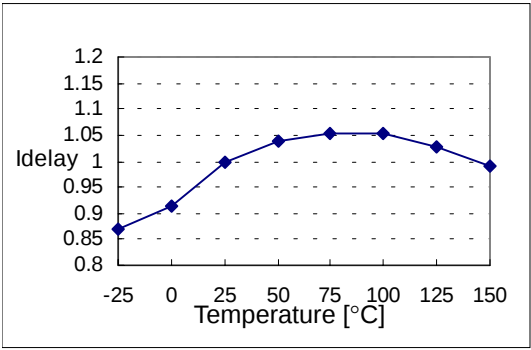


Figure 11. Shutdown Delay Current

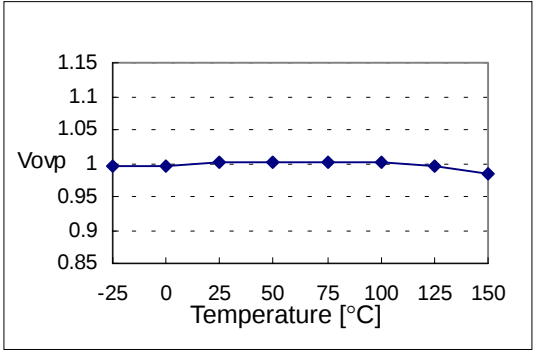


Figure 12. Over Voltage Protection

## Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at  $T_a=25^\circ\text{C}$ )

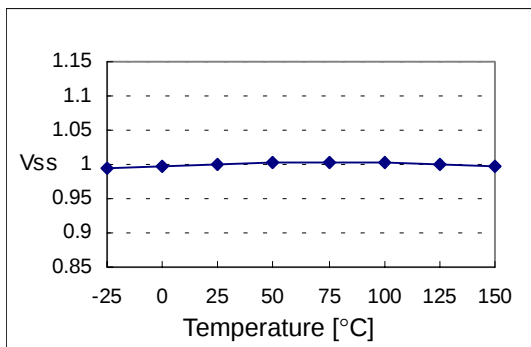


Figure13. Soft Start Voltage

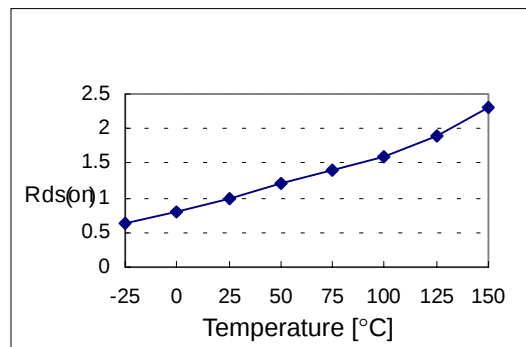
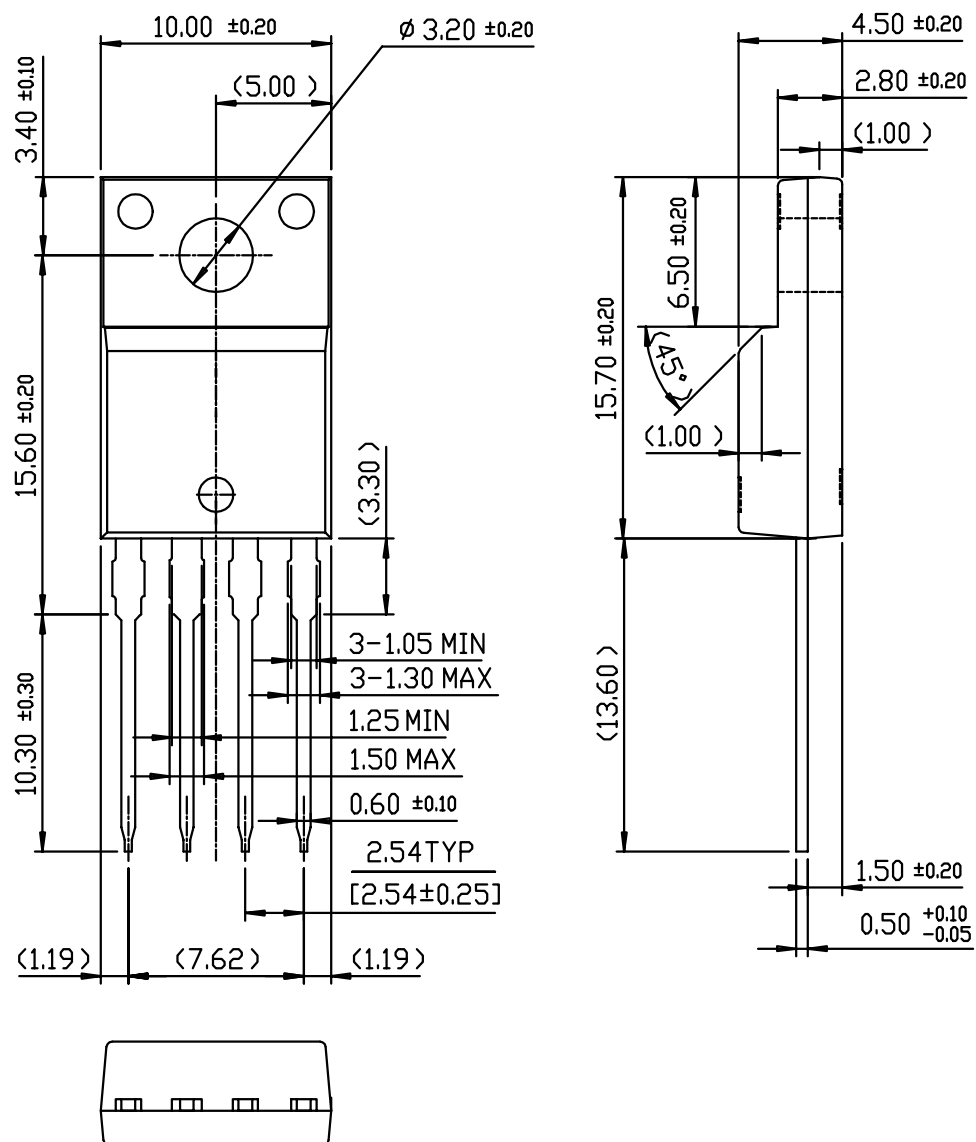


Figure 14. Static Drain-Source on Resistance

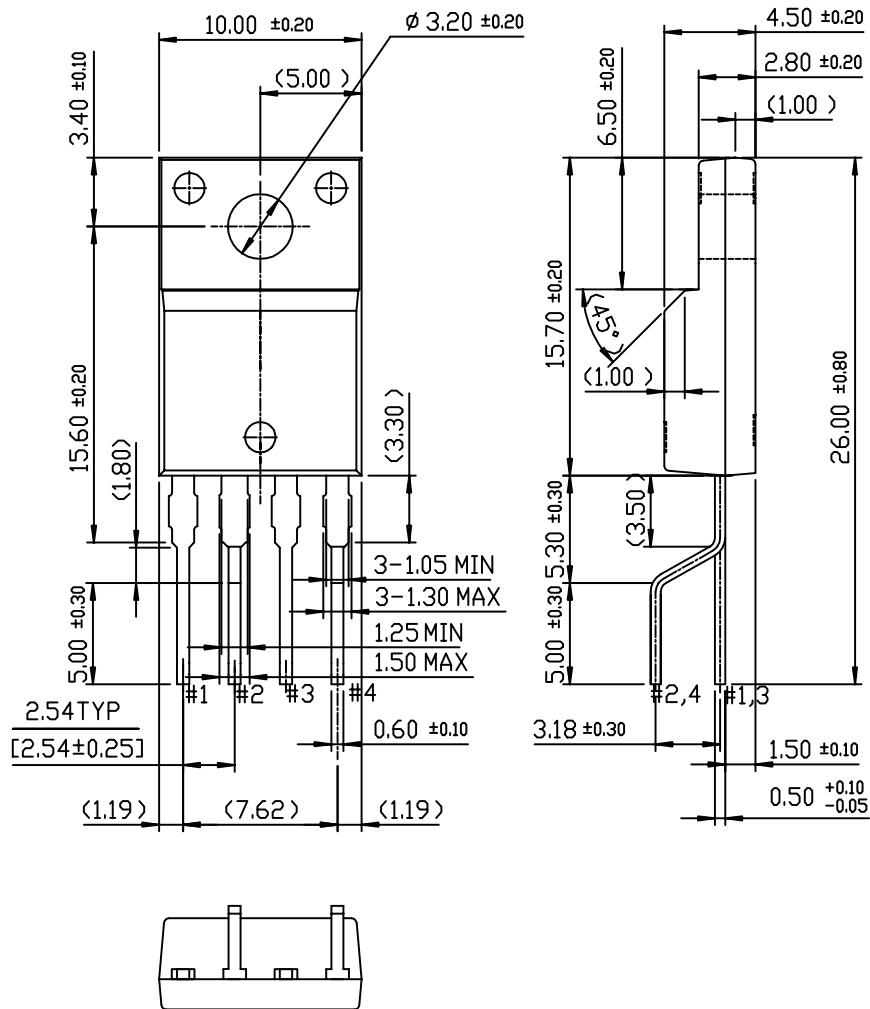
## Package Dimensions

## TO-220F-4L



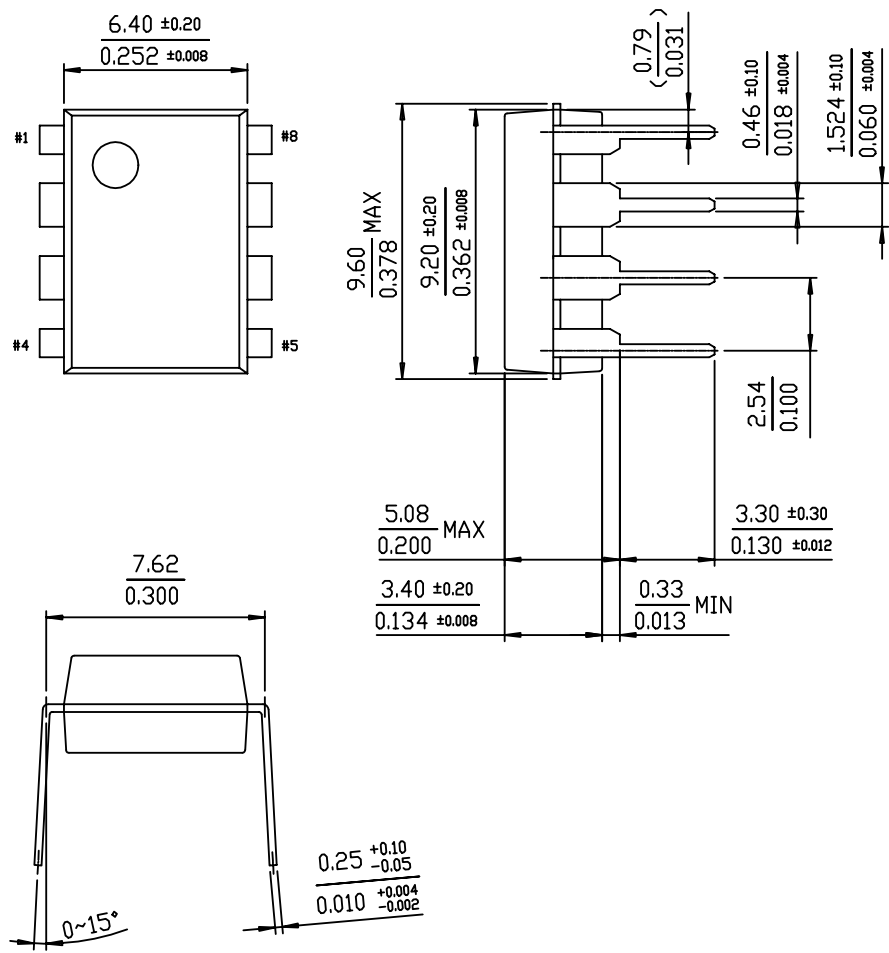
## Package Dimensions (Continued)

## TO-220F-4L(Forming)



Package Dimensions (Continued)

8-DIP



[illegible]

Technical drawing of the 2000 Series 1000V Molded Case Circuit Breaker (MCCB) showing front, side, and top views with dimensions in millimeters.

**Front View Dimensions:**

- Overall width:  $9.88 \pm 0.20$
- Internal width:  $(8.70)$
- Top flange width:  $1.30 \pm 0.10$
- Top flange thickness:  $(1.70)$
- Mounting hole diameter:  $\varnothing 3.60 \pm 0.10$
- Mounting hole offset:  $2.80 \pm 0.10$
- Internal vertical spacing:  $(3.70)$
- Internal vertical spacing:  $(4.60)$
- Internal vertical spacing:  $(3.00)$
- Internal vertical spacing:  $15.90 \pm 0.20$
- Internal vertical spacing:  $18.70 \pm 0.20$
- Terminal block height:  $10.30 \pm 0.20$
- Terminal block width:  $(0.93)$
- Terminal block thickness:  $1.10 \text{ TYP}$
- Terminal block offset:  $2-1.30 \text{ MAX}$  (#1,#5)
- Terminal block offset:  $0.80 \text{ TYP}$
- Terminal block offset:  $3-1.00 \text{ MAX}$  (#2,#3,#4)
- Terminal block offset:  $5-0.60 \pm 0.10$
- Terminal block offset:  $2.54 \text{ TYP}$  [2.54 ± 0.20]
- Terminal block offset:  $3-1.50 \text{ TYP}$  [3-1.50 ± 0.20]
- Terminal block offset:  $2.40 \pm 0.20$

**Side View Dimensions:**

- Overall height:  $26.00 \pm 0.80$
- Top flange height:  $4.50 \pm 0.20$
- Top flange offset:  $1.30^{+0.10}_{-0.05}$
- Internal vertical spacing:  $15.70 \pm 0.20$
- Internal vertical spacing:  $5.30 \pm 0.50$
- Internal vertical spacing:  $5.00 \pm 0.50$
- Internal vertical spacing:  $3.18 \pm 0.30$
- Internal vertical spacing:  $0.50^{+0.10}_{-0.05}$
- Internal vertical spacing:  $2.40 \pm 0.20$

**Top View Dimensions:**

- Overall width:  $10.00 \pm 0.20$

## Ordering Information

| Product Number  | Package             | Marking Code | BVDSS | FOSC   | RDS(on) |
|-----------------|---------------------|--------------|-------|--------|---------|
| KA5H0265RC-TU   | TO-220-5L           | 5H0265RC     | 650V  | 100kHz | 5Ω      |
| KA5H0265RC-YDTU | TO-220-5L(Forming)  |              |       |        |         |
| KA5M0265R-TU    | TO-220F-4L          | 5M0265R      | 650V  | 67kHz  | 5Ω      |
| KA5M0265R-YDTU  | TO-220F-4L(Forming) |              |       |        |         |
| KA5L0265R-TU    | TO-220F-4L          | 5L0265R      | 650V  | 50kHz  | 5Ω      |
| KA5L0265R-YDTU  | TO-220F-4L(Forming) |              |       |        |         |

| Product Number | Package             | Marking Code | BVDSS | FOSC   | RDS(on) |
|----------------|---------------------|--------------|-------|--------|---------|
| KA5H0280R-TU   | TO-220F-4L          | 5H0280R      | 800V  | 100kHz | 5.6Ω    |
| KA5H0280R-YDTU | TO-220F-4L(Forming) |              |       |        |         |
| KA5M0280R-TU   | TO-220F-4L          | 5M0280R      | 800V  | 67kHz  | 5.6Ω    |
| KA5M0280R-YDTU | TO-220F-4L(Forming) |              |       |        |         |
| Product Number | Package             | Marking Code | BVDSS | FOSC   | RDS(on) |
| KA5H02659RN    | 8-DIP               | 5H02659R     | 650V  | 100kHz | 5Ω      |
| KA5M02659RN    | 8-DIP               | 5M02659R     | 650V  | 67kHz  | 5Ω      |

TU : Non Forming Type

YDTU : Forming Type

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.